SMALL SIGNAL SCHOTTKY DIODES

勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-54151736 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw

FEATURES

N.100Y.COM.

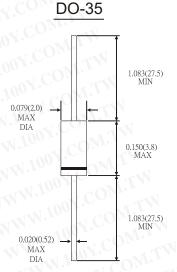
- · For general purpose applications
- These diodes features very low turn-on voltage and fast switching. These devices are protected by a PN junction guard ring against excessive voltage, such as electrostatic discharges.
- This diode is also available in the Mini-MELF case with type designation LL85.in the Micro-MELF case with type designation MCL85

MECHANICAL DATA

Case: DO-35 glass case

· Polarity: color band denotes cathode end

Weight: Approx. 0.13 gram



ABSOLUTE RATINGS(LIMITING VALUES)

Dimensions in inches and (millimeters)

	Symbols	Value	Units
Repetitive Peak Reverse Voltage	VR	30	V
orward Continuous Current at TA=25°C	IF. OUT	200 ¹⁾	mA
Repetitive Peak Forward Current at $t_0 < 1s$, $\delta < 0.5$, $t_A = 25^{\circ}C$	IFM .	300 ¹⁾	mA
urge forward current at tp < 10mS , TA=25°C	İFSM	600 ¹⁾	mA
Power Dissipation ¹⁾ at T _A =65°C	Ptot	200 1)	mW
unction temperature	TJ.	125	°
mbient Operating temperature Range	TA	-65 to+125	°C
orage Temperature Range	Tstg	-65 to+150	°C (
Valid provided that leads at a distance of 4mm from case are kept a	t ambient temperature		

WWW.100Y.COM.TW

ELECTRICAL CHARACTERISTICS

. T.M. 100	Symbols	Min.	Typ.	Max.	Units
Reverse breakdown voltage Tested with 100µA pulses	V(BR)R	30	V 10	01.	V
Forward voltage Pulse Test $t_{\rm b} < 300 \mu s, \delta < 2\%$ at $t_{\rm e} = 0.1 m A$, at $t_{\rm e} = 10 m A$.	VF VF VF VF	LM LM	0.50	0.24 0.32 0.4 0.8	V V V V
Leakage current V _R =25V	IR.	TIN	WW	2	μА
Junction Capacitance at V _R =1V ,f=1MHz	Jun Ci	1.1		10	pF
Reverse recovery time Form I _F =10mA,I _R =10mA,I _R =1mA	trr	WILL		5	ns
Thermal resistance junction to ambient Air	Reja	1		300 ¹⁾	K/W

WWW.100Y.COM.T